



Data sheet acquired from Harris Semiconductor SCHS085

CMOS Programmable Timer High Voltage Types (20V Rating)

Features

- Low Symmetrical Output Resistance, Typically 100 Ω at V_{DD} = 15V
- Built-In Low-Power RC Oscillator
- Oscillator Frequency Range..... DC to 100kHz
- External Clock (Applied to Pin 3) can be Used Instead of Oscillator
- Operates as 2^N Frequency Divider or as a Single-Transition Timer
- Q/Q Select Provides Output Logic Level Flexibility
- AUTO or MASTER RESET Disables Oscillator During Reset to Reduce Power Dissipation
- Operates With Very Slow Clock Rise and Fall Times
- Capable of Driving Six Low Power TTL Loads, Three Low-Power Schottky Loads, or Six HTL Loads Over the Rated Temperature Range
- Symmetrical Output Characteristics
- 100% Tested for Quiescent Current at 20V
- . 5V, 10V, and 15V Parametric Ratings
- Meets All Requirements of JEDEC Standard No. 13B, "Standard Specifications for Description of 'B' Series CMOS Devices"

Ordering Information

| PART NUMBER | TEMP. RANGE (°C) | PACKAGE | PKG. NO. |
|-------------|---------------------|--------------|-------------|
| CD4541BF | -55 to 125 | 14 Ld CERDIP | F14.3 |
| CD4541BE | -55 to 125 | 14 Ld PDIP | E14.3 |
| CD4541BH | -55 to 125 | Chip | - |
| CD4541BM | -55 to 125 | 14 Ld SOIC | M14.15 |

Description

CD4541B programmable timer consists of a 16-stage binary counter, an oscillator that is controlled by external R-C components (2 resistors and a capacitor), an automatic power-on reset circuit, and output control logic. The counter increments on positive-edge clock transitions and can also be reset via the MASTER RESET input.

The output from this timer is the Q or \overline{Q} output from the 8th, 10th, 13th, or 16th counter stage. The desired stage is chosen using time-select inputs A and B (see Frequency Select Table). The output is available in either of two modes selectable via the MODE input, pin 10 (see Truth Table). When this MODE input is a logic "1", the output will be a continuous square wave having a frequency equal to the oscillator frequency divided by 2^N . With the MODE input set to logic "0" and after a MASTER RESET is initiated, the output (assuming Q output has been selected) changes from a low to a high state after 2^{N-1} counts and remains in that state until another MASTER RESET pulse is applied or the MODE input is set to a logic "1".

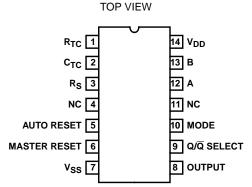
Timing is initialized by setting the AUTO RESET input (pin 5) to logic "0" and turning power on. If pin 5 is set to logic "1", the AUTO RESET circuit is disabled and counting will not start until after a positive MASTER RESET pulse is applied and returns to a low level. The AUTO RESET consumes an appreciable amount of power and should not be used if low-power operation is desired. For reliable automatic power-on reset, $V_{\mbox{\scriptsize DD}}$ should be greater than 5V.

The RC oscillator, shown in Figure 2, oscillates with a frequency determined by the RC network and is calculated using:

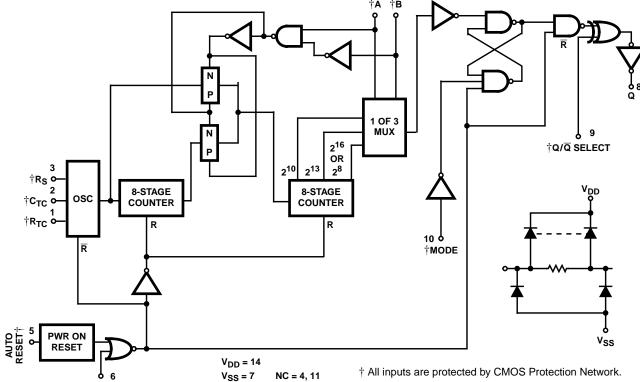
$$f = \frac{1}{2.3 \ R_{TC} C_{TC}} \qquad \begin{array}{l} \text{Where f is between 1kHz} \\ \text{and 100kHz} \\ \text{and } R_{\c S} \ge 10 k\Omega \ \text{and} \approx 2 R_{\c TC} \end{array}$$

Pinout

CD4541B (CERDIP, PDIP, SOIC)



Functional Diagram R_S AR 5 MR 10 **V_{DD}** = **PIN** 14 MODE -V_{SS} = PIN 7 Q/Q SELECT Functional Block Diagram 12 13 †A †B



MANUAL RESETT

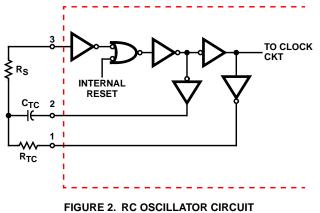
FIGURE 1.

FREQUENCY SELECTION TABLE

| А | В | NO. OF STAGES N | COUNT 2 ^N |
|---|---|--------------------|----------------------|
| 0 | 0 | 13 | 8192 |
| 0 | 1 | 10 | 1024 |
| 1 | 0 | 8 | 256 |
| 1 | 1 | 16 | 65536 |

TRUTH TABLE

| | STATE | | | | | | | |
|-----|---|---|--|--|--|--|--|--|
| PIN | 0 | 1 | | | | | | |
| 5 | Auto Reset On | Auto Reset Disable | | | | | | |
| 6 | Master Reset Off | Master Reset On | | | | | | |
| 9 | Output Initially Low After Reset (Q) | Output Initially High After Reset $(\overline{\mathbb{Q}})$ | | | | | | |
| 10 | Single Transition Mode | Recycle Mode | | | | | | |



CD4541B

Absolute Maximum Ratings

Thermal Information Thermal Pacietance (Typical, Note 1)

| Thermal Resistance (Typical, Note 1) | θ_{JA} (°C/W) | θ_{JC} (oC/W) |
|--|----------------------|--------------------------------------|
| PDIP Package | 90 | N/A |
| CERDIP Package | 90 | 36 |
| SOIC Package | 120 | N/A |
| Maximum Junction Temperature (Plastic F | Package) | 150 ^o C |
| Maximum Storage Temperature Range (T | STG)65 | ^o C to 150 ^o C |
| Maximum Lead Temperature (Soldering 1 | 0s) | |
| At Distance $1/16$ in $\pm 1/32$ in $(1.59$ mm ± 0 |).79mm) | |
| from case for 10s Maximum | | 265 ⁰ C |
| (SOIC - Lead Tips Only) | | |

Operating Conditions

For $T_A = Full Package Temperature Range 3V (Min), 18V (Typ)$

CAUTION: Stresses above those listed in "Absolute Maximum Ratings" may cause permanent damage to the device. This is a stress only rating and operation of the device at these or any other conditions above those indicated in the operational sections of this specification is not implied.

NOTE:

1. $\theta_{\mbox{\scriptsize JA}}$ is measured with the component mounted on an evaluation PC board in free air.

Electrical Specifications

| | CONDITIONS | | | | LIMITS AT INDICATED TEMPERATURES (°C) | | | | | | |
|--|--------------------|------------------------|------------------------|-------|---------------------------------------|-------|-------|-------|------|------|-------|
| | V | v | V | | | | | 25 | | | 1 |
| PARAMETER | V _O (V) | V _{IN} (V) | V _{DD} (V) | -55 | -40 | 85 | 125 | MIN | TYP | MAX | UNITS |
| Quiescent Device | - | 0, 5 | 5 | 5 | 5 | 150 | 150 | - | 0.04 | 5 | μА |
| Current, (Note 2) I _{DD} (Max) | - | 0, 10 | 10 | 10 | 10 | 300 | 300 | - | 0.04 | 10 | μΑ |
| | - | 0, 15 | 15 | 20 | 20 | 600 | 600 | - | 0.04 | 20 | μΑ |
| | - | 0, 20 | 20 | 100 | 100 | 3000 | 3000 | - | 0.08 | 100 | μΑ |
| Output Low (Sink) | 0.4 | 0, 5 | 5 | 1.9 | 1.85 | 1.26 | 1.08 | 1.55 | 3.1 | - | μΑ |
| Current I _{OL} (Min) | 0.5 | 0, 10 | 10 | 5 | 4.8 | 3.3 | 2.8 | 4 | 8 | - | μΑ |
| | 1.5 | 0, 15 | 15 | 12.6 | 12 | 8.4 | 7.2 | 10 | 20 | - | μА |
| Output High (Source) | 4.6 | 0, 5 | 5 | -1.9 | -1.85 | -1.26 | -1.08 | -1.55 | -3.1 | - | mA |
| Current, I _{OH} (Min) | 2.5 | 0, 5 | 5 | -6.2 | -6 | -4.1 | -3 | -5 | -10 | - | mA |
| | 9.5 | 0, 10 | 10 | -5 | -4.8 | -3.3 | -2.8 | -4 | -8 | - | mA |
| | 13.5 | 0, 15 | 15 | -12.6 | -12 | -8.4 | -7.2 | -10 | -20 | - | mA |
| Output Voltage: | - | 0, 5 | 5 | - | | 0.05 | | - | 0 | 0.05 | mA |
| Low-Level, V _{OL} (Max) | - | 0, 10 | 10 | - | | 0.05 | | - | 0 | 0.05 | mA |
| | - | 0, 15 | 15 | - | | 0.05 | | - | 0 | 0.05 | mA |
| Output Voltage: | - | 0, 5 | 5 | - | | 4.95 | | 4.95 | 5 | - | mA |
| High-Level, V _{OH} (Min) | - | 0, 10 | 10 | - | | 9.95 | | 9.95 | 10 | - | mA |
| | - | 0, 15 | 15 | - | | 14.95 | | 14.95 | 15 | - | mA |
| Input Low Voltage, | 0.5, 4.5 | - | 5 | - | | 1.5 | | - | - | 1.5 | ٧ |
| V _{IL} (Max) | 1, 9 | - | 10 | - | | 3 | | - | - | 3 | V |
| | 1.5, 13.5 | - | 15 | - | | 4 | | - | - | 4 | ٧ |

CD4541B

Electrical Specifications (Continued)

| CONDITIONS | | | LIMITS AT INDICATED TEMPERATURES (°C) | | | | | | | | |
|--------------------------------------|-----------------------|------------------------|---------------------------------------|------|------|-----|-----|-----|-------------------|------|-------|
| | V- | V | V | | | | | | 25 | | |
| PARAMETER | ν _ο (۷) | V _{IN} (V) | V _{DD} (V) | -55 | -40 | 85 | 125 | MIN | TYP | MAX | UNITS |
| Input High Voltage, | 0.5, 4.5 | - | 5 | - | | 3.5 | | 3.5 | - | - | V |
| V _{IH} (Min) | 1, 9 | - | 10 | - | | 7 | | 7 | - | - | V |
| | 1.5, 13.5 | - | 15 | - | | 11 | | 11 | - | - | V |
| Input Current, I _{IN} (Max) | - | 0, 18 | 18 | ±0.1 | ±0.1 | ±1 | ±1 | - | ±10 ⁻⁵ | ±0.1 | μΑ |

NOTE:

2. With AUTO RESET enabled, additional current drain at 25°C is:

 $7\mu A$ (Typ), $200\mu A$ (Max) at 5V; $30\mu A$ (Typ), $350\mu A$ (Max) at 10V; $80\mu A$ (Typ), $500\mu A$ (Max) at 15V

Dynamic Electrical Specifications $T_A = 25^{\circ}C$, Input t_r , $t_f = 20$ ns, $C_L = 50$ pF, $R_L = 200$ k Ω

| PARAMETER | SYMBOL | V _{DD} (V) | MIN | TYP | MAX | UNITS |
|--|--|---------------------|-----|------|------|-------|
| Propagation Delay Times Clock to Q | (2 ⁸) t _{PHL} , t _{PLH} | 5 | - | 3.5 | 10.5 | μs |
| | | 10 | - | 1.25 | 3.8 | μs |
| | | 15 | - | 0.9 | 2.9 | μs |
| | (2 ¹⁶) t _{PHL} , t _{PLH} | 5 | - | 6.0 | 18 | μs |
| | | 10 | - | 3.5 | 10 | μs |
| | | 15 | - | 2.5 | 7.5 | μs |
| Transition Time | t _{THL} | 5 | - | 100 | 200 | ns |
| | | 10 | - | 50 | 100 | ns |
| | | 15 | - | 40 | 80 | ns |
| | t _{THL} | 5 | - | 180 | 360 | ns |
| | | 10 | - | 90 | 180 | ns |
| | | 15 | - | 65 | 130 | ns |
| MASTER RESET, CLOCK | | 5 | 900 | 300 | - | ns |
| Pulse Width | | 10 | 300 | 100 | - | ns |
| | | 15 | 225 | 85 | - | ns |
| Maximum Clock Pulse Input | f _{CL} | 5 | - | 1.5 | - | MHz |
| Frequency | | 10 | - | 4 | - | MHz |
| | | 15 | - | 6 | - | MHz |
| Maximum Clock Pulse Input Rise or Fall time | t _r , t _f | 5, 10, 15 | | μs | | |

Digital Timer Application

A positive pulse on MASTER RESET resets the counters and latch. The output goes high and remains high until the number of pulses, selected by A and B, are counted. This circuit is retriggerable and is as accurate as the input frequency. If additional accuracy is desired, an external clock can be used on pin 3. A setup time equal to the width of the one-shot output is required immediately following initial power up, during which time the output will be high.

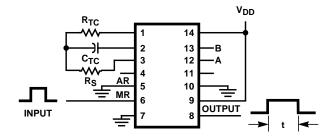
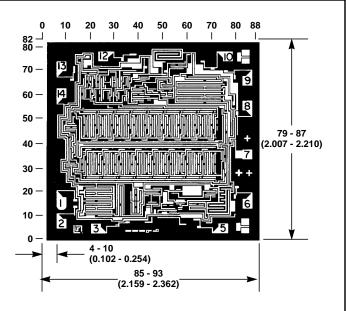


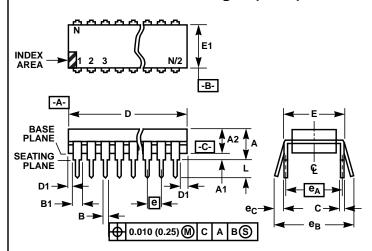
FIGURE 3. DIGITAL TIMER APPLICATION CIRCUIT



NOTE: Dimensions in parentheses are in millimeters and are derived from the basic inch dimensions as indicated. Grid graduations are in mils (10⁻³ inch).

FIGURE 4. DIMENSIONS AND PAD LAYOUT FOR CD4541B

Dual-In-Line Plastic Packages (PDIP)



NOTES:

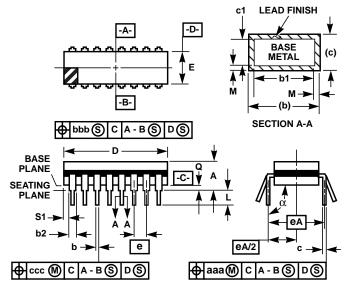
- Controlling Dimensions: INCH. In case of conflict between English and Metric dimensions, the inch dimensions control.
- 2. Dimensioning and tolerancing per ANSI Y14.5M-1982.
- 3. Symbols are defined in the "MO Series Symbol List" in Section 2.2 of Publication No. 95.
- 4. Dimensions A, A1 and L are measured with the package seated in JEDEC seating plane gauge GS-3.
- D, D1, and E1 dimensions do not include mold flash or protrusions.
 Mold flash or protrusions shall not exceed 0.010 inch (0.25mm).
- 6. E and $\boxed{e_A}$ are measured with the leads constrained to be perpendicular to datum $\boxed{-C_-}$.
- 7. e_B and e_C are measured at the lead tips with the leads unconstrained. e_C must be zero or greater.
- 8. B1 maximum dimensions do not include dambar protrusions. Dambar protrusions shall not exceed 0.010 inch (0.25mm).
- 9. N is the maximum number of terminal positions.
- Corner leads (1, N, N/2 and N/2 + 1) for E8.3, E16.3, E18.3, E28.3, E42.6 will have a B1 dimension of 0.030 - 0.045 inch (0.76 - 1.14mm).

E14.3 (JEDEC MS-001-AA ISSUE D)
14 LEAD DUAL-IN-LINE PLASTIC PACKAGE

| | INC | HES | MILLIM | ETERS | |
|----------------|-------|-------|----------|----------|-------|
| SYMBOL | MIN | MAX | MIN | MAX | NOTES |
| Α | - | 0.210 | - | 5.33 | 4 |
| A1 | 0.015 | - | 0.39 | - | 4 |
| A2 | 0.115 | 0.195 | 2.93 | 4.95 | - |
| В | 0.014 | 0.022 | 0.356 | 0.558 | - |
| B1 | 0.045 | 0.070 | 1.15 | 1.77 | 8 |
| С | 0.008 | 0.014 | 0.204 | 0.355 | - |
| D | 0.735 | 0.775 | 18.66 | 19.68 | 5 |
| D1 | 0.005 | - | 0.13 | - | 5 |
| E | 0.300 | 0.325 | 7.62 | 8.25 | 6 |
| E1 | 0.240 | 0.280 | 6.10 | 7.11 | 5 |
| е | 0.100 | BSC | 2.54 BSC | | - |
| e _A | 0.300 | BSC | 7.62 | 7.62 BSC | |
| e _B | - | 0.430 | - | 10.92 | 7 |
| L | 0.115 | 0.150 | 2.93 | 3.81 | 4 |
| N | 1 | 4 | 1 | 4 | 9 |

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Ceramic Dual-In-Line Frit Seal Packages (CERDIP)



NOTES:

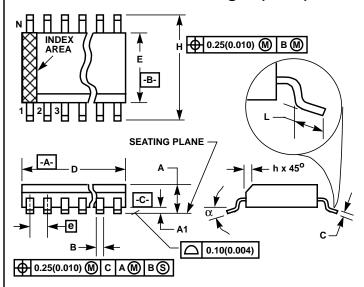
- Index area: A notch or a pin one identification mark shall be located adjacent to pin one and shall be located within the shaded area shown. The manufacturer's identification shall not be used as a pin one identification mark.
- The maximum limits of lead dimensions b and c or M shall be measured at the centroid of the finished lead surfaces, when solder dip or tin plate lead finish is applied.
- Dimensions b1 and c1 apply to lead base metal only. Dimension M applies to lead plating and finish thickness.
- Corner leads (1, N, N/2, and N/2+1) may be configured with a partial lead paddle. For this configuration dimension b3 replaces dimension b2.
- 5. This dimension allows for off-center lid, meniscus, and glass overrun.
- 6. Dimension Q shall be measured from the seating plane to the base plane.
- 7. Measure dimension S1 at all four corners.
- 8. N is the maximum number of terminal positions.
- 9. Dimensioning and tolerancing per ANSI Y14.5M 1982.
- 10. Controlling dimension: INCH.

F14.3 MIL-STD-1835 GDIP1-T14 (D-1, CONFIGURATION A) 14 LEAD CERAMIC DUAL-IN-LINE FRIT SEAL PACKAGE

| | INCHES | | MILLIM | ETERS | |
|--------|--------|------------------|-----------------|------------------|-------|
| SYMBOL | MIN | MAX | MIN | MAX | NOTES |
| А | - | 0.200 | - | 5.08 | - |
| b | 0.014 | 0.026 | 0.36 | 0.66 | 2 |
| b1 | 0.014 | 0.023 | 0.36 | 0.58 | 3 |
| b2 | 0.045 | 0.065 | 1.14 | 1.65 | - |
| b3 | 0.023 | 0.045 | 0.58 | 1.14 | 4 |
| С | 0.008 | 0.018 | 0.20 | 0.46 | 2 |
| c1 | 0.008 | 0.015 | 0.20 | 0.38 | 3 |
| D | - | 0.785 | - | 19.94 | 5 |
| Е | 0.220 | 0.310 | 5.59 | 7.87 | 5 |
| е | 0.100 | BSC | 2.54 BSC | | - |
| eA | 0.300 | BSC | 7.62 | - | |
| eA/2 | 0.150 | BSC | 3.81 BSC | | - |
| L | 0.125 | 0.200 | 3.18 | 5.08 | - |
| Q | 0.015 | 0.060 | 0.38 | 1.52 | 6 |
| S1 | 0.005 | - | 0.13 | - | 7 |
| α | 90° | 105 ⁰ | 90 ^o | 105 ⁰ | - |
| aaa | - | 0.015 | - | 0.38 | - |
| bbb | - | 0.030 | - | 0.76 | - |
| ссс | - | 0.010 | - | 0.25 | - |
| М | - | 0.0015 | - | 0.038 | 2, 3 |
| N | 1 | 4 | 1 | 4 | 8 |

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Small Outline Plastic Packages (SOIC)



NOTES:

- Symbols are defined in the "MO Series Symbol List" in Section 2.2 of Publication Number 95.
- 2. Dimensioning and tolerancing per ANSI Y14.5M-1982.
- Dimension "D" does not include mold flash, protrusions or gate burrs. Mold flash, protrusion and gate burrs shall not exceed 0.15mm (0.006 inch) per side.
- 4. Dimension "E" does not include interlead flash or protrusions. Interlead flash and protrusions shall not exceed 0.25mm (0.010 inch) per side.
- 5. The chamfer on the body is optional. If it is not present, a visual index feature must be located within the crosshatched area.
- 6. "L" is the length of terminal for soldering to a substrate.
- 7. "N" is the number of terminal positions.
- 8. Terminal numbers are shown for reference only.
- The lead width "B", as measured 0.36mm (0.014 inch) or greater above the seating plane, shall not exceed a maximum value of 0.61mm (0.024 inch).
- 10. Controlling dimension: MILLIMETER. Converted inch dimensions are not necessarily exact.

M14.15 (JEDEC MS-012-AB ISSUE C)
14 LEAD NARROW BODY SMALL OUTLINE PLASTIC
PACKAGE

| | INC | HES | MILLIM | ETERS | |
|--------|--------|----------------|--------|----------------|-------|
| SYMBOL | MIN | MAX | MIN | MAX | NOTES |
| Α | 0.0532 | 0.0688 | 1.35 | 1.75 | - |
| A1 | 0.0040 | 0.0098 | 0.10 | 0.25 | - |
| В | 0.013 | 0.020 | 0.33 | 0.51 | 9 |
| С | 0.0075 | 0.0098 | 0.19 | 0.25 | - |
| D | 0.3367 | 0.3444 | 8.55 | 8.75 | 3 |
| E | 0.1497 | 0.1574 | 3.80 | 4.00 | 4 |
| е | 0.050 | BSC | 1.27 | - | |
| Н | 0.2284 | 0.2440 | 5.80 | 6.20 | - |
| h | 0.0099 | 0.0196 | 0.25 | 0.50 | 5 |
| L | 0.016 | 0.050 | 0.40 | 1.27 | 6 |
| N | 14 | | 1 | 4 | 7 |
| α | 0° | 8 ⁰ | 0° | 8 ⁰ | - |

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